Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Plastic	
Overall Length:	
0.722 inches	
Overall Height:	
0.300 inches	
Joint Electronic De	evice Engineering Council/jedec/case Outline Designation:
To-116	
Component Name	And Quantity:
4 transistor	
Mounting Method:	
Terminal	
Semiconductor Ma	aterial:
Silicon all transistor	
Voltage Rating In V	Volts Per Characteristic:
30.0 collector to em	nitter voltage/static/base open all transistor and 60.0 collector to base voltage/static/emitter open all transistor and 5.0
emitter to base volta	age, static, collector open all transistor
Current Rating Per	r Characteristic:
500.00 milliamperes	s source cutoff current all transistor
Power Rating Per	Characteristic:
650.0 milliwatts sma	all-signal input power, common-collector preset all transistor
Transfer Ratio:	
30.0 static forward	current transfer ratio, common-emitter all transistor
Maximum Operatir	ng Tempurature Per Measurement Point:
200.0 degrees celsi	us junction
Terminal Type And	d Quantity:
14 pin	
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
A110a0	